DS90LV017A LVDS Single High Speed Differential Driver

Check for Samples: DS90LV017A

FEATURES

- **>600 Mbps (300 MHz) Switching Rates**
- **0.3 ns Typical Differential Skew**
- **0.7 ns Maximum Differential Skew**
- **1.5 ns Maximum Propagation Delay**
- **3.3V Power Supply Design**
- **±355 mV Differential Signaling**
- **Low Power Dissipation (23 mW @ 3.3V Static)**
- **Flow-Through Design Simplifies PCB Layout**
- **Interoperable with Existing 5V LVDS Devices**
- **Power Off Protection (Outputs in High Impedance)**
- **Conforms to TIA/EIA-644 Standard**
- **8-Lead SOIC Package Saves Space**
- **Industrial Temperature Operating Range**
  - **(−40°C to +85°C)**

DESCRIPTION

The DS90LV017A is a single LVDS driver device optimized for high data rate and low power applications. The DS90LV017A is a current mode driver allowing power dissipation to remain low even at high frequency. In addition, the short circuit fault current is also minimized. The device is designed to support data rates in excess of 600Mbps (300MHz) utilizing Low Voltage Differential Signaling (LVDS) technology.

The device is in a 8-lead SOIC package. The DS90LV017A has a flow-through design for easy PCB layout. The differential driver outputs provides low EMI with its typical low output swing of 355 mV. The DS90LV017A can be paired with its companion single line receiver, the DS90LV018A, or with any of TI's LVDS receivers, to provide a high-speed point-to-point LVDS interface.

Connection Diagram

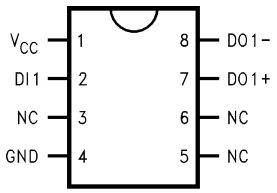
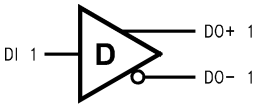


Figure 1. Dual-In-Line
See Package Number D (R-PDSO-G8)

Functional Diagram



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings(1)

Supply Voltage (V_{CC})		−0.3V to +4V
Input Voltage (DI)		−0.3V to +3.6V
Output Voltage (DO±)		−0.3V to +3.9V
Maximum Package Power Dissipation @ +25°C	D Package	1190 mW
	Derate D Package	9.5 mW/°C above +25°C
Storage Temperature Range		−65°C to +150°C
Lead Temperature Range Soldering (4 sec.)		+260°C
ESD Ratings	(HBM 1.5 kΩ, 100 pF)	≥ 8kV
	(EIAJ 0 Ω, 200 pF)	≥ 1000V
	(CDM)	≥ 1000V
	(IEC direct 330 Ω, 150 pF)	≥ 4kV

(1) "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be ensured. They are not meant to imply that the devices should be operated at these limits. Electrical Characteristics specifies conditions of device operation.

Recommended Operating Conditions

	Min	Typ	Max	Units
Supply Voltage (V_{CC})	3.0	3.3	3.6	V
Temperature (T_A)	−40	25	+85	°C

Electrical Characteristics

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified(1)(2)(3)

Symbol	Parameter	Conditions		Pin	Min	Typ	Max	Units
DIFFERENTIAL DRIVER CHARACTERISTICS								
V_{OD}	Output Differential Voltage	R_L = 100Ω (Figure 2)		DO+, DO−	250	355	450	mV
ΔV_{OD}	V_{OD} Magnitude Change					1	35	mV
V_{OH}	Output High Voltage					1.4	1.6	V
V_{OL}	Output Low Voltage				0.9	1.1		V
V_{OS}	Offset Voltage				1.125	1.2	1.375	V
ΔV_{OS}	Offset Magnitude Change				0	3	25	mV
I_{OXD}	Power-off Leakage	V_{OUT} = V_{CC} or GND, V_{CC} = 0V				±1	±10	µA
I_{OSD}	Output Short Circuit Current					−5.7	−8	mA
V_{IH}	Input High Voltage			DI	2.0		V_{CC}	V
V_{IL}	Input Low Voltage				GND		0.8	V
I_{IH}	Input High Current	V_{IN} = 3.3V or 2.4V				±2	±10	µA
I_{IL}	Input Low Current	V_{IN} = GND or 0.5V				±1	±10	µA
V_{CL}	Input Clamp Voltage	I_{CL} = −18 mA			−1.5	−0.6		V
I_{CC}	Power Supply Current	No Load	V_{IN} = V_{CC} or GND	V_{CC}		5	8	mA
		R_L = 100Ω				7	10	mA

(1) Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground except V_{OD}.
(2) All typicals are given for: V_{CC} = +3.3V and T_A = +25°C.
(3) The DS90LV017A is a current mode device and only function with datasheet specification when a resistive load is applied to the drivers outputs.

Switching Characteristics

Over Supply Voltage and Operating Temperature Ranges, unless otherwise specified(1)(2)(3)(4)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
DIFFERENTIAL DRIVER CHARACTERISTICS						
t_{PHLD}	Differential Propagation Delay High to Low	R_L = 100Ω, C_L = 15 pF	0.3	0.8	1.5	ns
t_{PLHD}	Differential Propagation Delay Low to High	(Figure 3 and Figure 4)	0.3	1.1	1.5	ns
t_{SKD1}	Differential Pulse Skew $\|t_{PHLD} - t_{PLHD}\|$(5)		0	0.3	0.7	ns
t_{SKD3}	Differential Part to Part Skew(6)		0		1.0	ns
t_{SKD4}	Differential Part to Part Skew(7)		0		1.2	ns
t_{TLH}	Transition Low to High Time		0.2	0.5	1.0	ns
t_{THL}	Transition High to Low Time		0.2	0.5	1.0	ns
f_{MAX}	Maximum Operating Frequency(8)			350		MHz

(1) All typicals are given for: V_{CC} = +3.3V and T_A = +25°C.
(2) These parameters are ensured by design. The limits are based on statistical analysis of the device performance over PVT (process, voltage, temperature) ranges.
(3) C_L includes probe and fixture capacitance.
(4) Generator waveform for all tests unless otherwise specified: f = 1 MHz, Z_O = 50Ω, t_r ≤ 1 ns, t_f ≤ 1 ns (10%-90%).
(5) t_{SKD1}, $|t_{PHLD} - t_{PLHD}|$, is the magnitude difference in differential propagation delay time between the positive going edge and the negative going edge of the same channel.
(6) t_{SKD3}, Differential Part to Part Skew, is defined as the difference between the minimum and maximum specified differential propagation delays. This specification applies to devices at the same V_{CC} and within 5°C of each other within the operating temperature range.
(7) t_{SKD4}, part to part skew, is the differential channel to channel skew of any event between devices. This specification applies to devices over recommended operating temperature and voltage ranges, and across process distribution. t_{SKD4} is defined as |Max − Min| differential propagation delay.
(8) f_{MAX} generator input conditions: t_r = t_f < 1 ns (0% to 100%), 50% duty cycle, 0V to 3V. Output criteria: duty cycle = 45%/55%, V_{OD} > 250mV.

Parameter Measurement Information

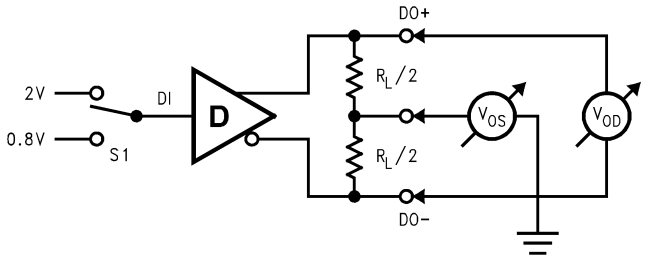


Figure 2. Differential Driver DC Test Circuit

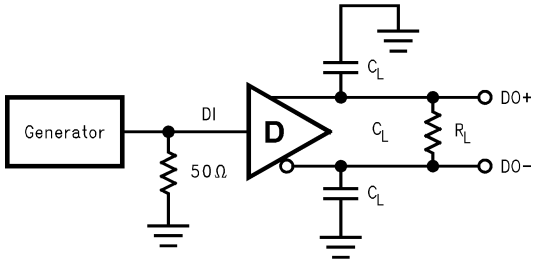


Figure 3. Differential Driver Propagation Delay and Transition Time Test Circuit

Parameter Measurement Information (continued)

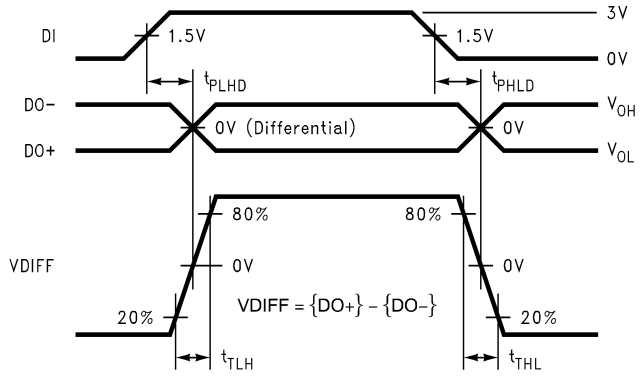


Figure 4. Differential Driver Propagation Delay and Transition Time Waveforms

APPLICATION INFORMATION

Table 1. Device Pin Descriptions

Pin #	Name	Description
2	DI1	TTL/CMOS driver input pins
7	DO1+	Non-inverting driver output pin
8	DO1−	Inverting driver output pin
4	GND	Ground pin
1	V_{CC}	Positive power supply pin, +3.3V ± 0.3V
3, 5, 6	NC	No connect

Typical Performance Curves

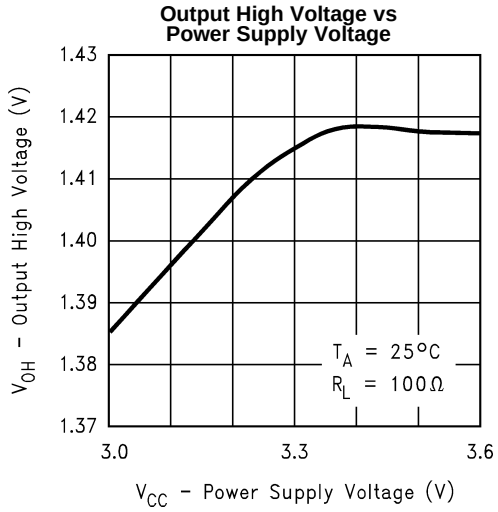


Figure 5.

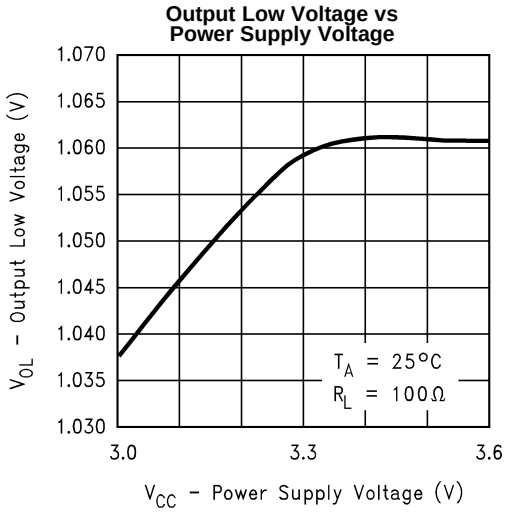


Figure 6.

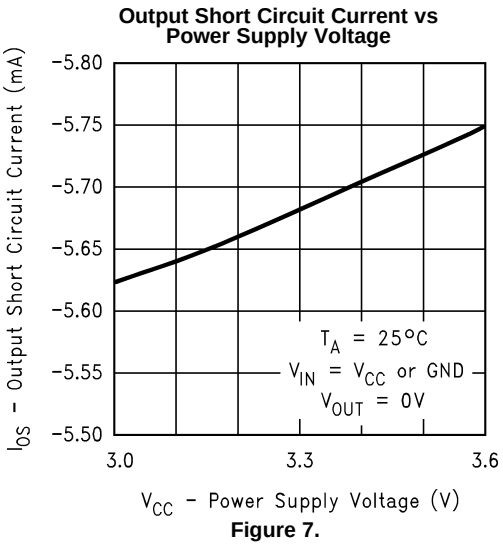


Figure 7.

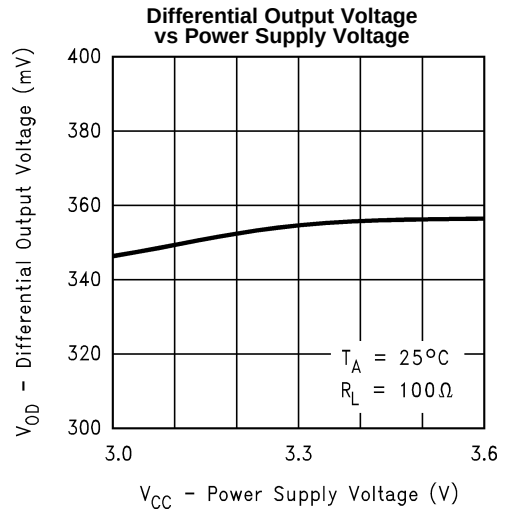


Figure 8.

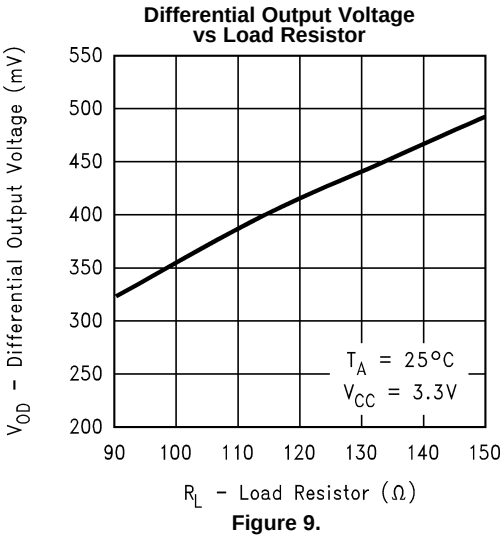


Figure 9.

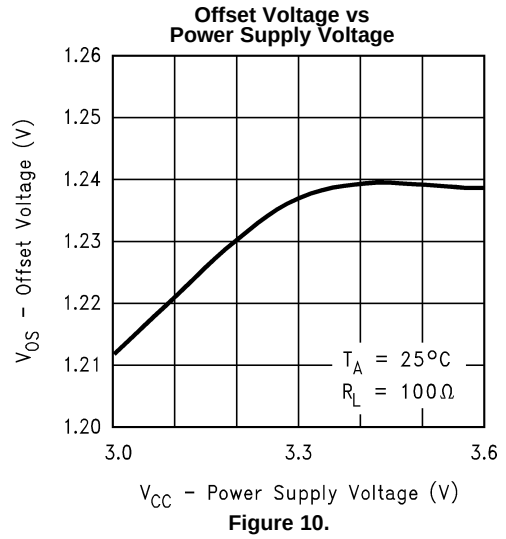


Figure 10.

Typical Performance Curves (continued)

Power Supply Current vs Frequency

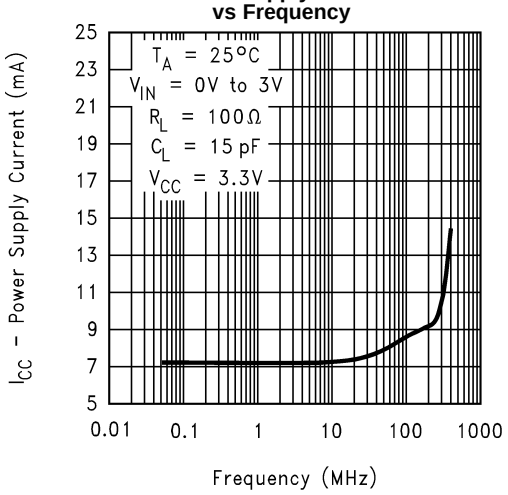


Figure 11.

Power Supply Current vs Power Supply Voltage

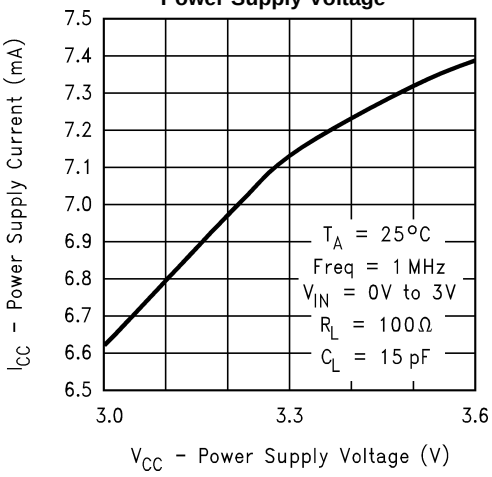


Figure 12.

Power Supply Current vs Ambient Temperature

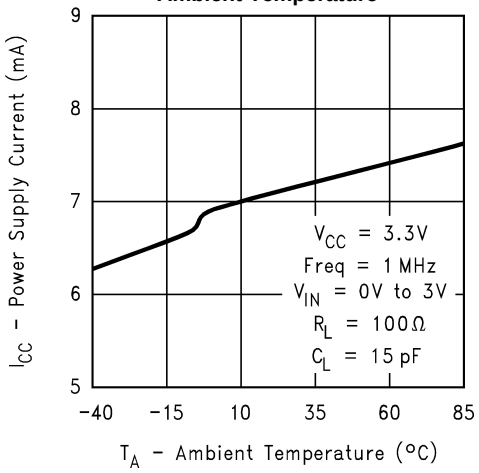


Figure 13.

Differential Propagation Delay vs Power Supply Voltage

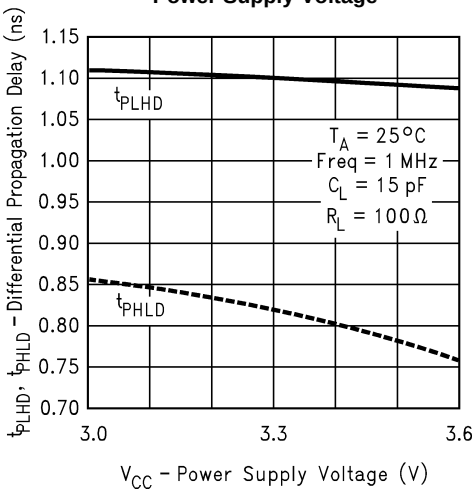


Figure 14.

Differential Propagation Delay vs Ambient Temperature

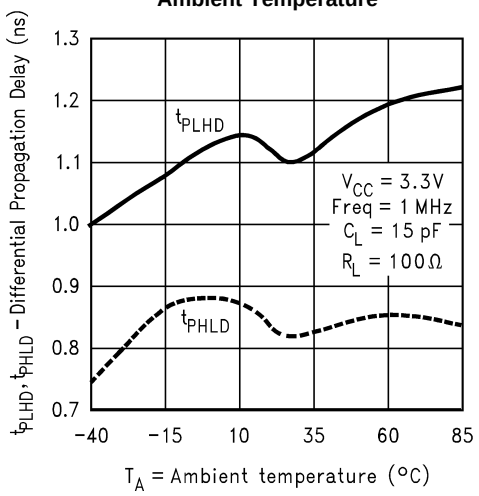


Figure 15.

Differential Skew vs Power Supply Voltage

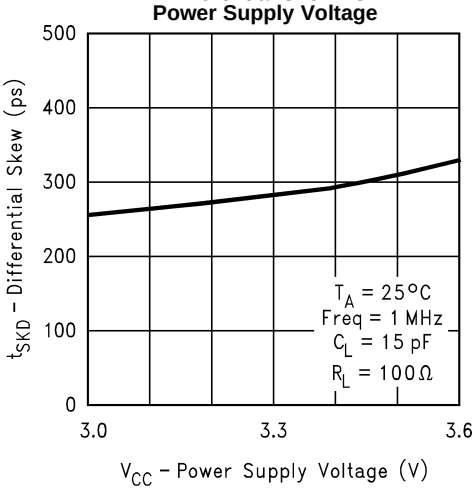


Figure 16.

Typical Performance Curves (continued)

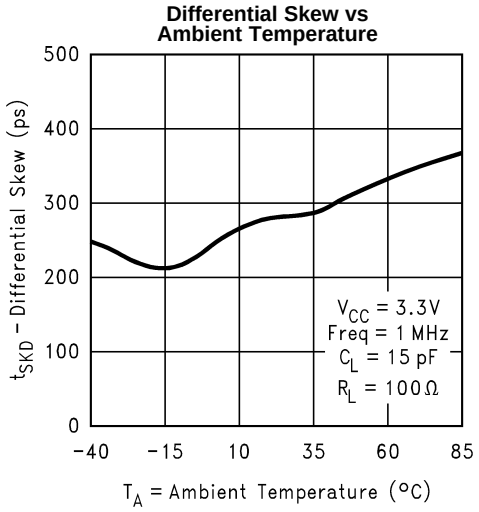


Figure 17.

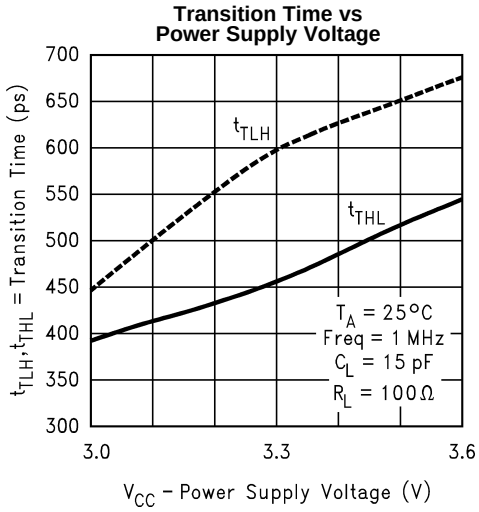


Figure 18.

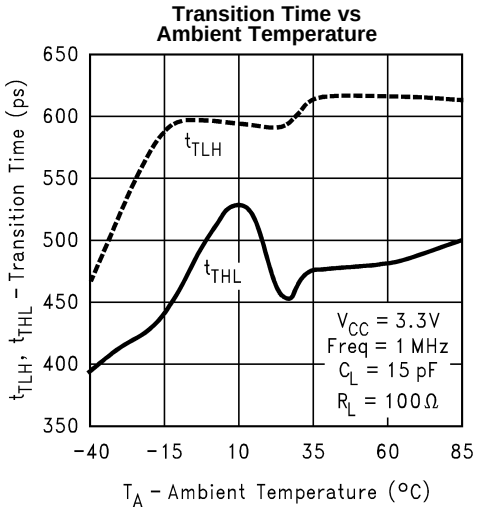


Figure 19.

REVISION HISTORY

Changes from Revision B (April 2013) to Revision C	Page
• Changed layout of National Data Sheet to TI format	7

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
DS90LV017ATM	NRND	SOIC	D	8	95	Non-RoHS & Green	Call TI	Level-1-235C-UNLIM	-40 to 85	LV17A TM	
DS90LV017ATM/NOPB	ACTIVE	SOIC	D	8	95	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	LV17A TM	Samples
DS90LV017ATMX/NOPB	ACTIVE	SOIC	D	8	2500	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	LV17A TM	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

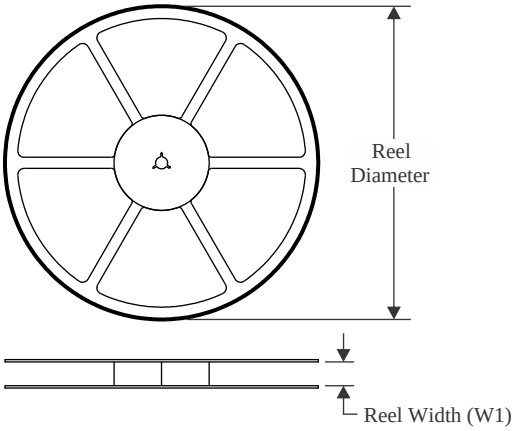
(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

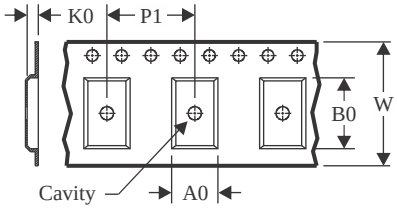
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

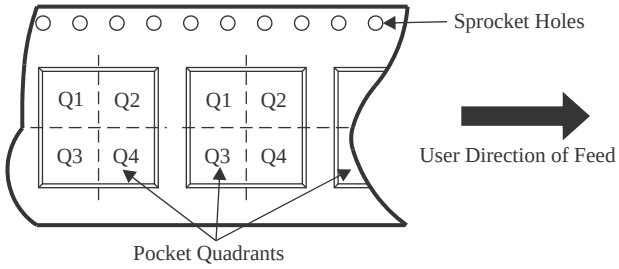


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

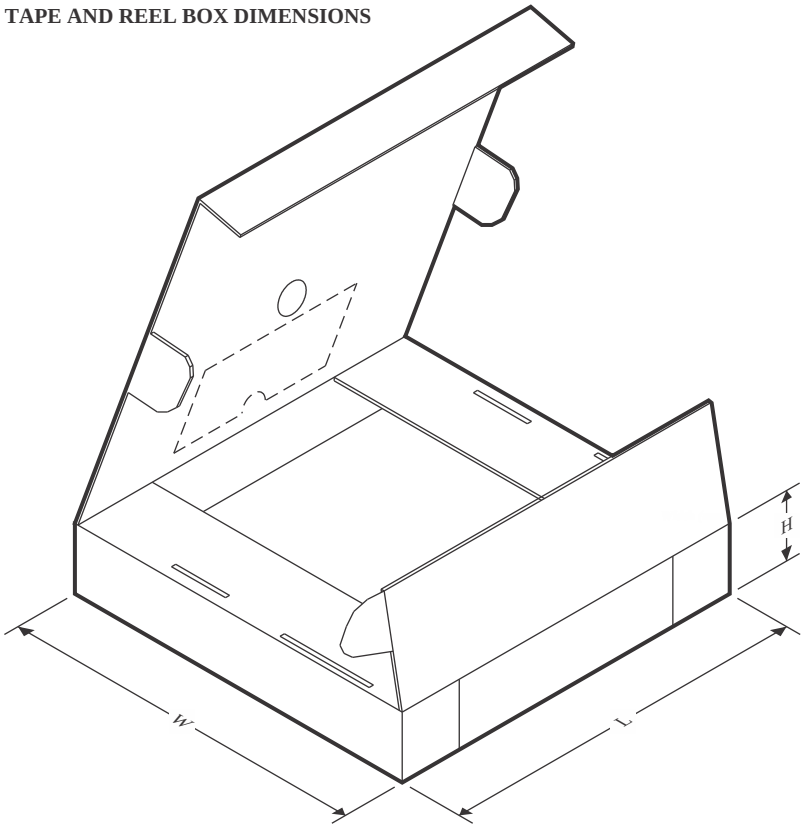
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DS90LV017ATMX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

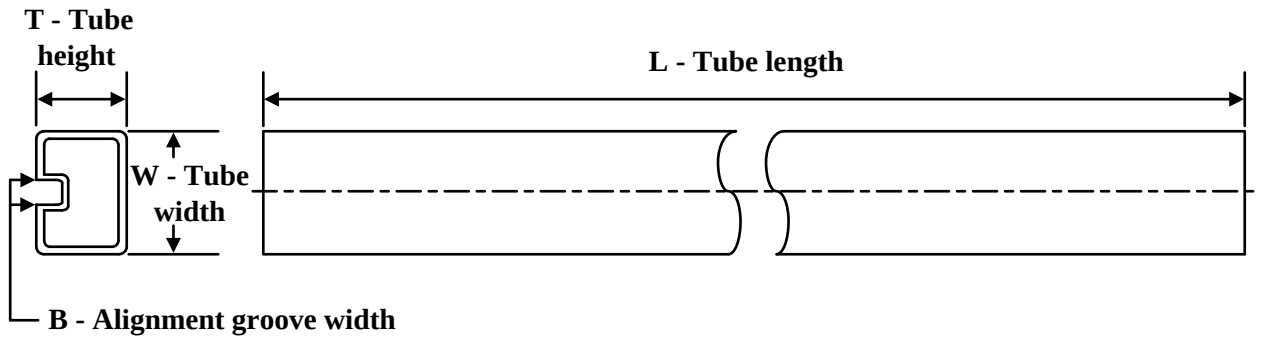
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

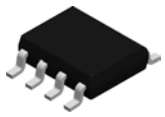
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DS90LV017ATMX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
DS90LV017ATM	D	SOIC	8	95	495	8	4064	3.05
DS90LV017ATM	D	SOIC	8	95	495	8	4064	3.05
DS90LV017ATM/NOPB	D	SOIC	8	95	495	8	4064	3.05

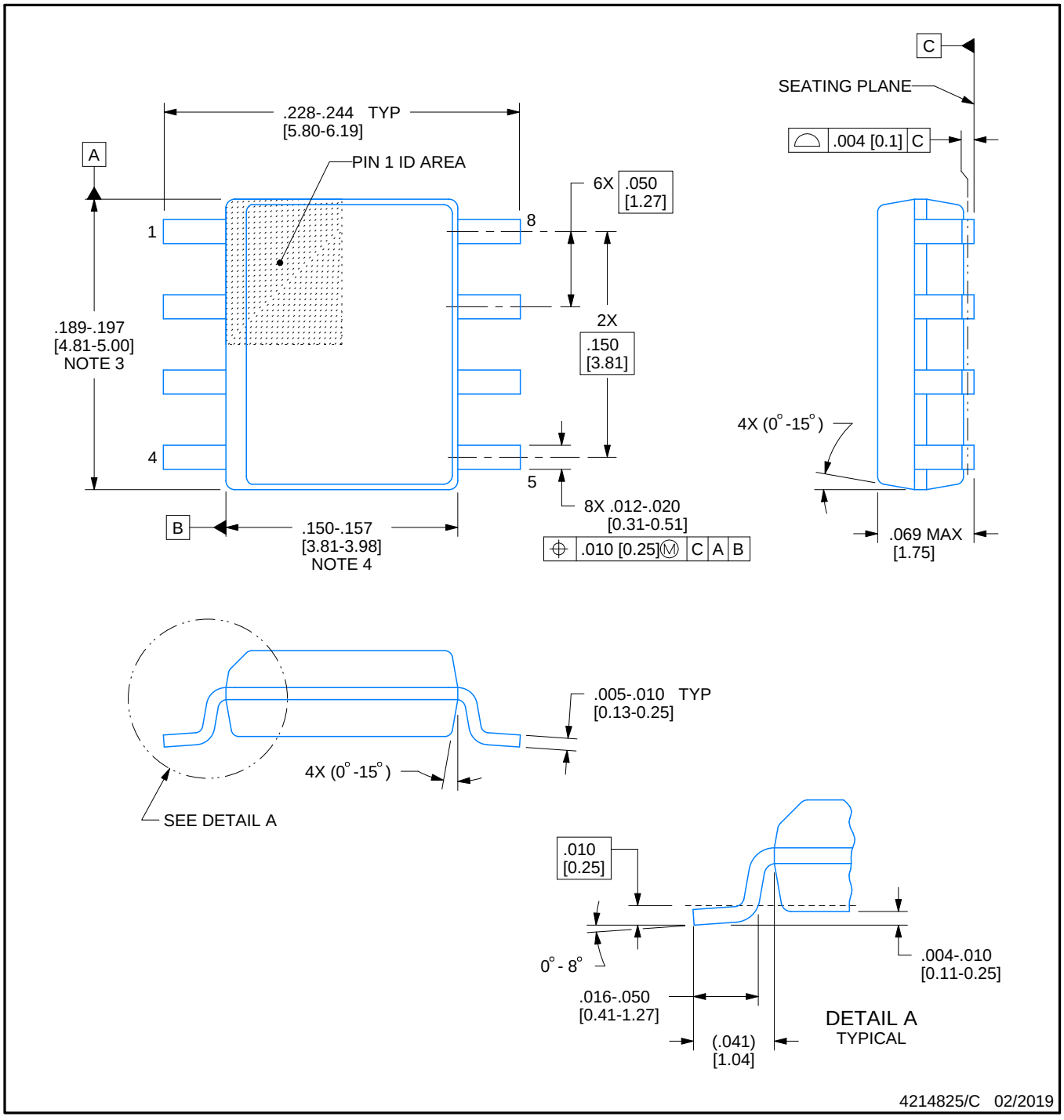


PACKAGE OUTLINE

D0008A

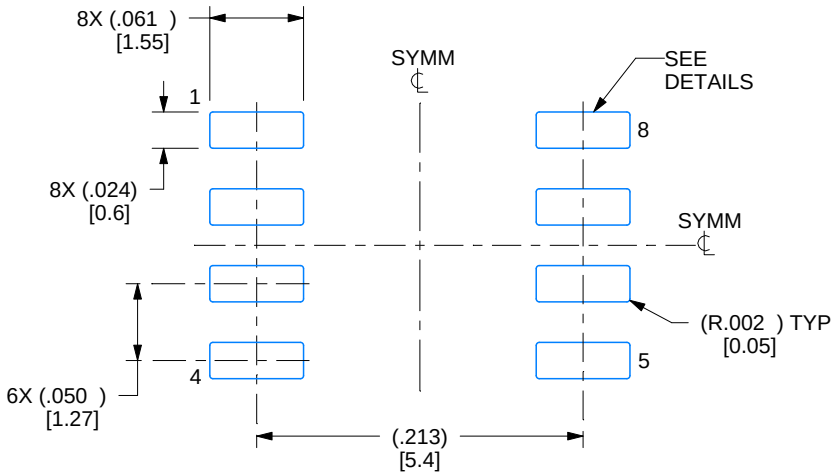
SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

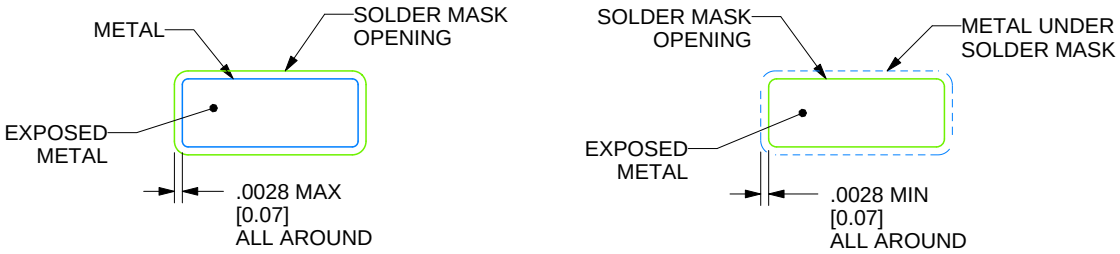


NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

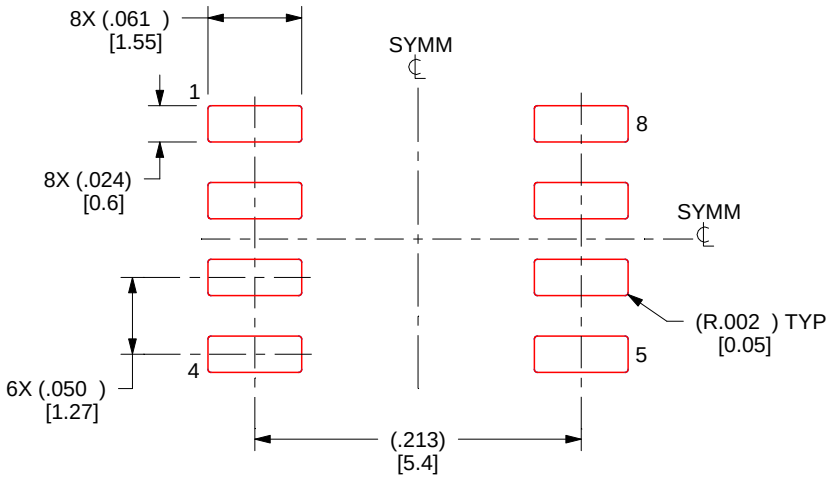
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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